PQ1Uxx1M2ZP Series

PQ1Uxx1M2ZP Series

■ Features

- 1. Compact surface mount package (2.9×1.6×1.1mm)
- 2. Low power-loss

(Dropout voltage:TYP. 0.11 V at Io=60mA)

- 3. High ripple rejection (TYP. 60dB)
- Built-in ON/OFF control function
 (Dissipation current at OFF-state:MAX. 1μA)
- 6. Overcurrent, overheat protection functions
- *It is available for every 0.1V(1.8V to 5.5V)

■ Applications

- 1. Cellular phones
- 2. Cordless phones
- 3. Personal information tools(PDA)
- 4. Cameras/Camcoders
- 5. PCMCIA cards for notebook PCs

■ Model Line-up

Output Voltage (TYP.)	Model No.	Output Voltage (TYP.)	Model No.
2.5V	PQ1U251M2ZP	3.5V	PQ1U351M2ZP
2.8V	PQ1U281M2ZP	3.6V	PQ1U361M2ZP
3.0V	PQ1U301M2ZP	3.8V	PQ1U381M2ZP
3.3V	PQ1U331M2ZP	4.0V	PQ1U401M2ZP
3.4V	PQ1U341M2ZP	5.0V	PQ1U501M2ZP

■ Absolute Maximum Ratings

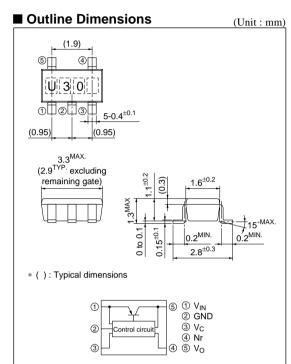
Parameter	Symbol	Rating	Unit
*1 Input voltage	Vin	16	V
*1Output control voltage	Vc	16	V
Output current	Io	300	mA
*2 Power dissipation	PD	350	mW
*3 Junction temperature	Tj	150	°C
Operating temperature	Topr	-30 to +80	°C
Storage temperature	Tstg	-55 to +150	°C

 T_{sol}

260 (10s)

Soldering temperature

Low Output Current, Compact Surface Mount Type Low Power-Loss Voltage Regulators



(Ta=25°C)

^{*1} All are open except GND and applicable terminals, refer to Fig.3

^{*2} At mounting PCB

^{*3} Overheat protection may operate at the condition Tj:125°C to 150°C

■ Electrical Characteristics	(Unl	ess otherwise specified, V _{IN} =V _O (TYP)+1	.0V, Io=	30mA, V	c=1.8V,	Γa=25°C)
Parameter	Symbol	Conditions MIN. TYP.		MAX.	Unit	
Output voltage	Vo	_	Refer to the following table.1		V	
*4 Output peak current	Iop	_	180	300	_	mA
Recommended output current	_	_	_	_	150	mA
	RegL1	Io=5 to 60mA	_	10	50	mV
Load regulation	RegL2	Io=5 to 100mA	_	20	100	mV
	RegL3	Io=5 to 150mA	_	30	160	mV
Line regulation	RegI	V _{IN} =V _O (TYP)+1V to V _O (TYP)+6V	P)+6V - 3.0 2		20	mV
Temperature coefficient of output voltage	TcVo	Io=10mA, T _j =-25 to +75°C - 0.05		_	mV/°C	
Ripple rejection	RR	Refer to Fig.2	- 70 -		dB	
Output noise voltage	V _{no (rms)}	10Hz <f<100khz, c<sub="">n=0.1μF, Io=30mA</f<100khz,>	- 70 - Refer to the following table.2		μV	
Durant valta a	V _I -o1	Io=60mA *5	- 0.11 0.26		0.26	v
Dropout voltage	V _{I-} o2	Io=150mA*5 - 0.20		0.4	\ \ \	
*6 ON-state voltage for control	V _C (ON)	_	1.8	_	-	V
ON-state current for control	Ic (on)	Vc=1.8V	_	5	30	μΑ
OFF-state voltage for control	V _C (OFF)	_	_	_	0.4	V
Quiescent current	Iq	Io=0mA	_	130	200	μΑ
Output OFF-state dissipation current	Ias	Vc=0.2V	_	_	1	цА

^{*4} Output current shall be the value when output voltage lowers 0.3V from the voltage at Io=30mA

Table.1 Output Voltage Line-up

(V_{IN}=V_O(TYP)+1.0V, Io=30mA, V_C=1.8V, Ta=25°C)

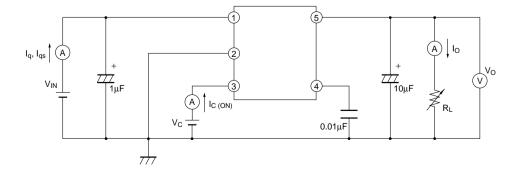
Model No.	Symbol	MIN.	TYP.	MAX.	Unit
PQ1U251M2ZP	Vo	2.440	2.5	2.560	V
PQ1U281M2ZP	Vo	2.740	2.8	2.860	V
PQ1U301M2ZP	Vo	2.940	3.0	3.060	V
PQ1U331M2ZP	Vo	3.234	3.3	3.366	V
PQ1U341M2ZP	Vo	3.332	3.4	3.468	V
PQ1U351M2ZP	Vo	3.430	3.5	3.570	V
PQ1U361M2ZP	Vo	3.528	3.6	3.672	V
PQ1U381M2ZP	Vo	3.724	3.8	3.876	V
PQ1U401M2ZP	Vo	3.920	4.0	4.080	V
PQ1U501M2ZP	Vo	4.900	5.0	5.100	V

Fig.1 Standard Test Circuit

Table.2 Output Noise Voltage Line-up

 $(V_{IN} = V_0(TYP) + 1.0V, I_0 = 30mA, V_0 = 1.8V, C_n = 0.1 \mu F, 10Hz < f < 100kHz, Ta = 25^{\circ}C)$

Model No.	Symbol	MIN.	TYP.	MAX.	Unit
PQ1U251M2ZP	V _{no(rms)}	-	25	_	V
PQ1U281M2ZP	V _{no(rms)}	_	25	_	V
PQ1U301M2ZP	V _{no(rms)}	_	30	_	V
PQ1U331M2ZP	V _{no(rms)}	_	30	_	V
PQ1U341M2ZP	V _{no(rms)}	_	30	_	V
PQ1U351M2ZP	V _{no(rms)}	_	35	_	V
PQ1U361M2ZP	V _{no(rms)}	-	35	_	V
PQ1U381M2ZP	V _{no(rms)}	_	35	_	V
PQ1U401M2ZP	V _{no(rms)}	_	40	_	V
PQ1U501M2ZP	V _{no(rms)}	_	50	_	V



^{**} Output culticulus siana to the value which output voltage when output voltage when output voltage falls 0.1V from that at Vin=Vo(TYP)+1.0V.

*6 In case that the control terminal (③ pin) is non-connection, output voltage should be OFF state.

Fig.2 Test Circuit for Ripple Rejection

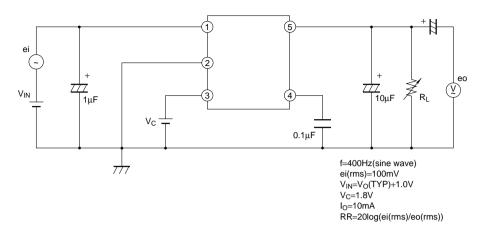


Fig.3 Power Dissipation vs. Ambient Temperature

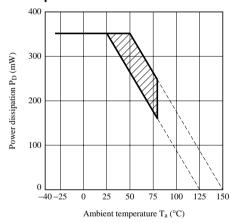


Fig.5 Output Voltage Fluctuation vs. Junction Temperature (PQ1U281M2ZP)(Typical Value)

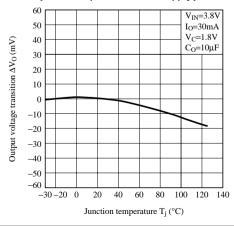


Fig.4 Overcurrent Protection Characteristics (Typical Value)

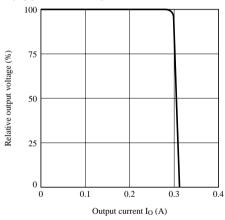


Fig.6 Output Voltage vs. Input Voltage (PQ1U281M2ZP)(Typical Value)

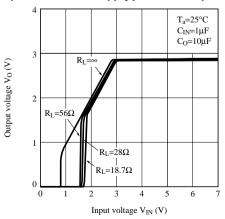


Fig.7 Operating Consumption Current vs. Input Voltage (PQ1U281M2ZP)(Typical Value)

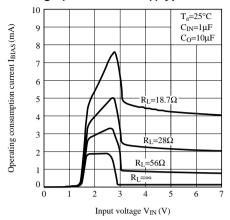


Fig.9 Quiescent Current vs. Junction Temperature (Typical Value)

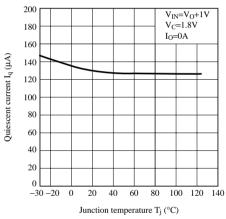


Fig.11 Dropout Voltage vs. Output Current

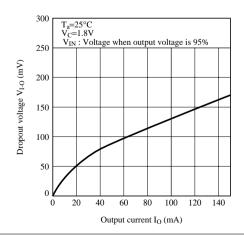


Fig.8 Dropout Voltage vs. Junction Temperature (PQ1U281M2ZP)(Typical Value)

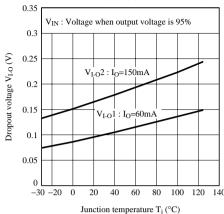


Fig.10 Ripple Rejection vs. Input Frequency (PQ1U281M2ZP)(Typical Value)

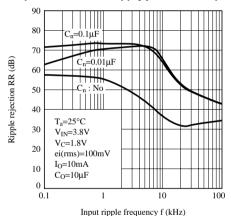
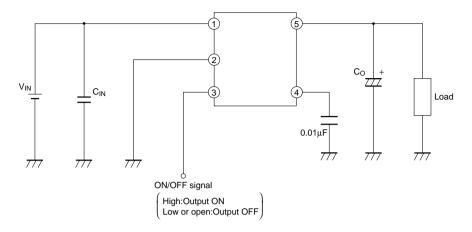


Fig.12 Example of Application



1. External connection

- (1) Please perform shortest wiring for connection between C₀ or Cin and the individual terminal. There is case that oscillation occurs easily by kinds of capacity capacity and how to wire. Before you use this device, you should confirm output voltage in your actual using conditions.
- (2) The input terminal for ON/OFF output control is compatible with LS-TTL, and direct driving by TTL or C-MOS standard logic (RCA 4000 series) is also available.
- (3) If voltage is applied under the conditions that the device pin is connected divergently or reversely, the deterioration of characteristics or damage may occur. Never allow improper mounting.

2. Thermal protection design

Maximum power dissipation of devices is obtained by the following equation.

$$P_D = V_{IN} \times I_{IN} - V_O \times I_O$$

When ambient temperature T_a and power dissipation P_D (MAX.) during operation are determined, use a heat sink which allows the element to operate within the safety operation area specified by the derating curve. Insufficient radiation gives an unfavorable influence to the normal operation and reliability of the device.

In the external area of the safety operation area shown by the derating curve, the overheat protection circuit may operate to shut-down output. However please avoid keeping such condition for a long time.

3. ESD (Electro Static Discharge)

Be careful not to apply electro static discharge to the device since this device employs a bipolar IC and may be damaged by electro static discharge. Followings are some methods against excessive voltage caused by electro static discharge.

- (1) Human body must be grounded to discharge the static electricity from the body or cloth.
- (2) Anything that is in contact with the device such as workbench, inserter, or measuring instrument must be grounded.
- (3) Use a solder dip basin with a minimum leak current (isolation resistance $10M\Omega$ or more) from the commercial power supply. Also the solder dip basin must be grounded.

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